

ABSOLUTE MAXIMUM RATINGS (Note 1)

Input Supply voltage, (+VIN) 40V
 Park/Inhibit, UV1 and UV2 inputs (zener clamped)
 Maximum forced voltage -0.3V to 10V
 Maximum forced current. ±10mA
 Other Input Voltages. -0.3V to +VIN
 ALSINK and BLSINK Voltages. -0.3V to 6V
 Open Collector Output Voltages. 40V
 A and B Output Currents (Continuous)
 Source Internally Limited
 Sink. 2.5A
 Total Supply Current (Continuous). 4A
 Parking Drive Output Current (Continuous). 200mA
 Supply OK Output Current, UC3177 (Continuous) . . . 30mA
 Operating Junction Temperature -55°C to +150°C
 Power Dissipation at TC = +75°C

 QP package. 4W
 Storage Temperature -65°C to +150°C

Note 1: Unless otherwise indicated, voltages are reference to ground and currents are positive into, negative out of, the specified terminals.

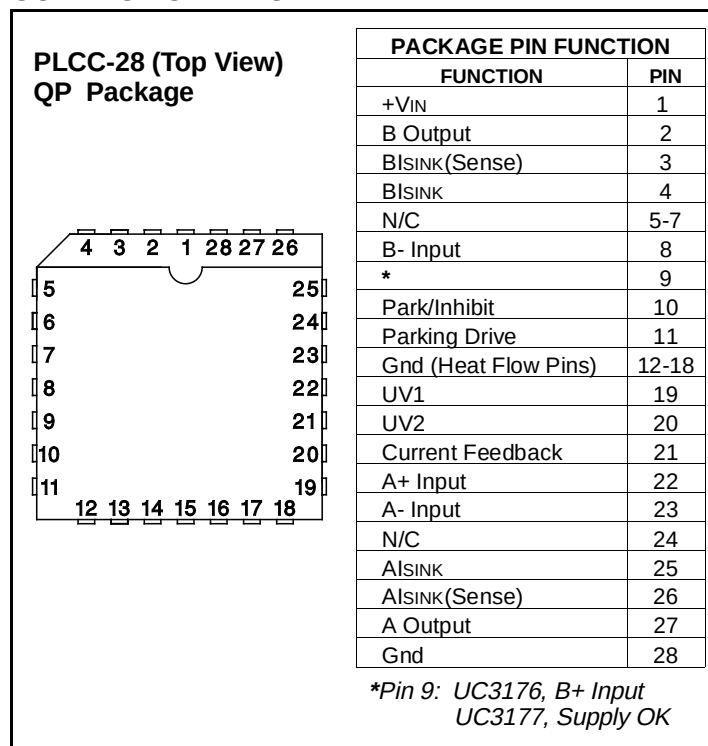
THERMAL DATA

QP package:

Thermal Resistance Junction to Leads, θ_{JL} 15°C/W

Thermal Resistance Junction to Ambient, θ_{JA} 50°C/W

CONNECTION DIAGRAM



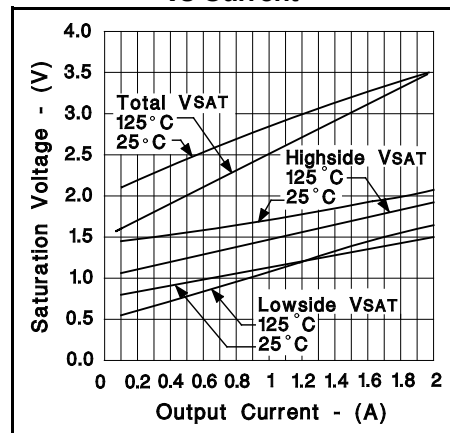
ELECTRICAL CHARACTERISTICS: Unless otherwise stated, specifications hold for $T_A = 0$ to 70°C , $+V_{IN} = 12\text{V}$, $T_A = T_J$.

PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Input Supply					
Supply Current	$+V_{IN} = 12\text{V}$		18	25	mA
	$+V_{IN} = 35\text{V}$		21	30	mA
UVOL Threshold	$+V_{IN}$ low to high		2.8	3.0	V
	Threshold Hysteresis		220	300	mV
Power, Amplifier, A and B					
Input Offset Voltage	$V_{CM} = 6\text{V}$, $V_{OUT} = 6\text{V}$			8	mV
Input Bias Current	$V_{CM} = 6\text{V}$, Except A+ Input	-500	-100		nA
Input Bias Current at A+/Reference Input	$(A+/Ref - BLSINK)/36\text{kohms}$; $T_J = 25^\circ\text{C}$	23	28	35	$\mu\text{A/V}$
Input Offset Current B Amp (UC3176 Only)	$V_{CM} = 6\text{V}$			200	nA
CMRR	$V_{CM} = 1$ to 33V , $+V_{IN} = 35\text{V}$, $V_{OUT} = 6\text{V}$	70	100		dB
PSRR	$+V_{IN} = 5$ to 35V , $V_{CM} = 2.5\text{V}$	70	100		dB
Large Signal Voltage Gain	$V_{OUT} = 3\text{V}$, $w/I_{OUT} = 1\text{A}$ to $V_{OUT} = 9\text{V}$, $w/I_{OUT} = -1\text{A}$	1.5	4		V/mV
Thermal Feedback	$+V_{IN} = 20\text{V}$, $P_d = 20\text{W}$ at opposite output		25	200	$\mu\text{V/W}$
Saturation Voltage	$I_{OUT} = -2\text{A}$, High Side, $T_J = 25^\circ\text{C}$		1.9		V
	$C_{IOUT} = 2\text{A}$, Low Side, $T_J = 25^\circ\text{C}$		1.6		V
	Total V_{SAT} at 2A , $T_J = 25^\circ\text{C}$		3.5	3.7	V
Unity Gain Bandwidth			1		MHz
Slew Rate			1		V/ μs
Differential I_{OUT} Sense Error Current in Bridge Configuration	$I_{OUT}(A) = -I_{OUT}(B)$, $I_{OUT}/-I_{ALSINK} - BLSINK/$				
	$I_{OUT} \leq 200\text{mA}$		3.0	6.0	mA
	$I_{OUT} \leq 2\text{A}$		5.0	10	mA
High Side Current Limiting	$=V_{IN} - V_{OUT} < 12\text{V}$		-2.7	-2.0	A

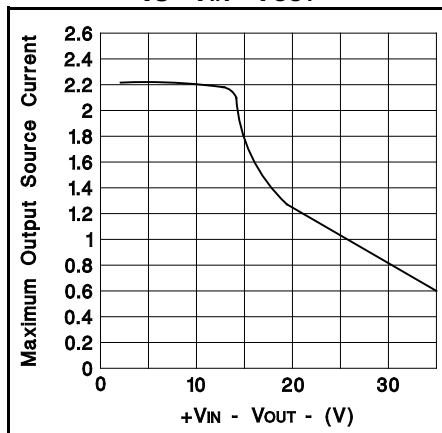
ELECTRICAL CHARACTERISTICS: Unless otherwise stated, specifications hold for $T_A = 0$ to 70°C , $+V_{IN} = 12\text{V}$, $T_A = T_J$.

PARAMETER	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Current Sense Amplifier					
Input Offset Voltage	$V_{CM} = 0\text{V}$, A+/Ref at 6V			3	mV
	Ref = 2V to 20V, $+V_{IN} = 35$, change with Ref input voltage			600	$\mu\text{V/V}$
Thermal Gradient Sensitivity	$+V_{IN} = 20\text{V}$, Ref = 10V Pd = 20W @ A or B output		5.0	75	$\mu\text{V/W}$
PSRR	Ref = 2.5V, $+V_{IN} = 5$ to 35V	70	100		dB
Gain	$ A_{ISINK} - B_{ISINK} \leq 0.5\text{V}$	7.8	8	8.1	V/V
Slew Rate			2		V/ μS
3dB Bandwidth			1		MHz
Max Output Current	$I_{SOURCE} = +V_{IN} - V_{OUT} = 0.5\text{V}$	2.5	3.5		mA
Output Saturation Voltage	$I_{SOURCE} = 1.5\text{mA}$, High Side		0.15	0.30	V
	$I_{SINK} = 5\text{mA}$, Low Side		1.4	1.7	V
Under-Voltage Comparator					
Threshold Voltage	Low to High, other input at 5V	1.44	1.50	1.56	V
	Threshold Hysteresis	50	70	80	mV
Input Current	Input = 2V, other input at 5V	-2	-.05		μA
Supply OK V_{SAT} (UC3177 Only)	$I_{OUT} = 5\text{mA}$			0.45	V
Supply OK Leakage (UC3177 Only)	$V_{OUT} = 35\text{V}$			5	μA
Park/Inhibit					
Park/Inhibit Thl'd		1.1	1.3	1.7	V
Park/Inhibit Input Current	At threshold		60	100	μA
Parking Drive Saturation Voltage	$I_{OUT} = 100\text{mA}$		0.3	0.7	V
Parking Drive Leakage	$V_{OUT} = 35\text{V}$			15	μA
Thermal Shutdown					
Shutdown Temperature			165		$^\circ\text{C}$

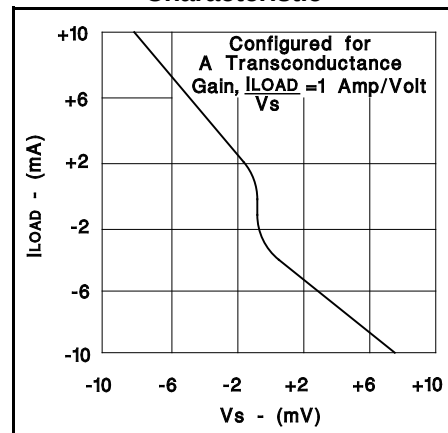
Output Saturation Voltage vs Current



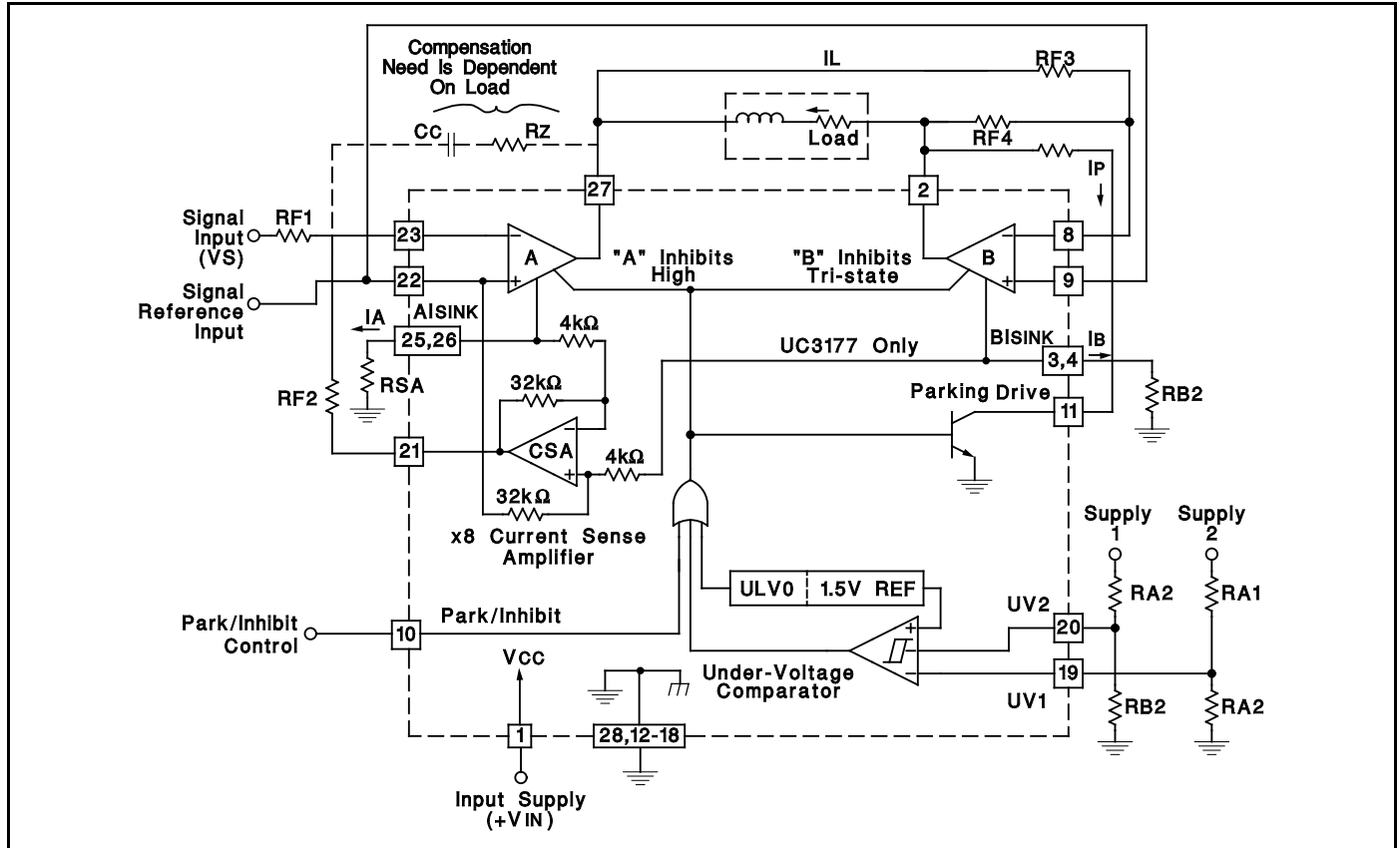
Maximum Source Current vs $+V_{IN} - V_{OUT}$



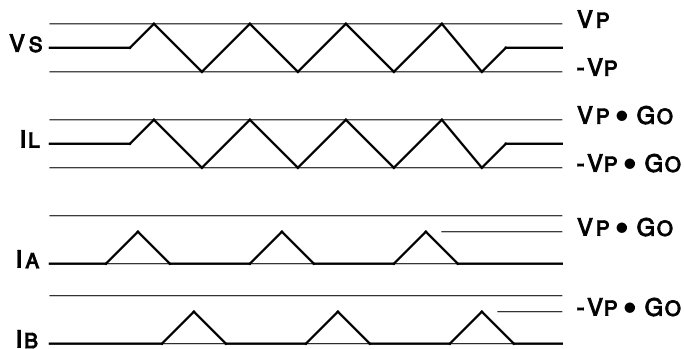
Crossover Current Error Characteristic



APPLICATION AND OPERATION INFORMATION



WAVEFORMS FOR ABOVE APPLICATION



DESIGN EQUATIONS

$$\text{Transconductance } (G_O) = \frac{I_L}{V_S} = \frac{R_{F2}}{R_{F1}} \times \left(\frac{1}{8R_S} \right)$$

with: $R_{SA} = R_{SB}$ and $R_{F3} = R_{F4}$

$$\text{Parking Current } (I_P) = \frac{V_{IN} - 1.5}{R_P + R_L}$$

where: R_L = load resistance

Under-Voltage Thresholds, at Supplies

High to Low Threshold, $(V_{LH}) = 1.425 (R_A + R_B)/R_B$

Low to High Threshold, $(V_{HL}) = 1.5 (R_A + R_B)/R_B$

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